

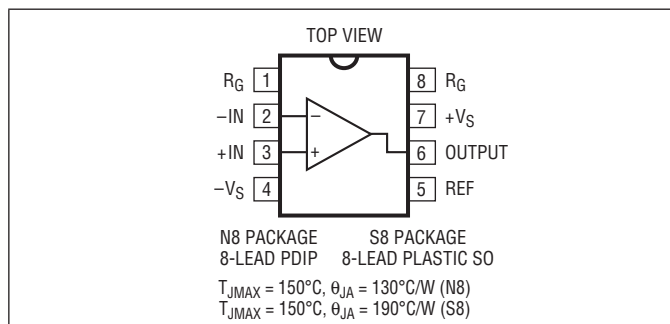
LT1167

ABSOLUTE MAXIMUM RATINGS

(Note 1)

Supply Voltage	$\pm 20V$
Differential Input Voltage (Within the Supply Voltage)	$\pm 40V$
Input Voltage (Equal to Supply Voltage).....	$\pm 20V$
Input Current (Note 3).....	$\pm 20mA$
Output Short-Circuit Duration	Indefinite
Operating Temperature Range	$-40^{\circ}C$ to $85^{\circ}C$
Specified Temperature Range	
LT1167AC/LT1167C/	
LT1167AC-1/LT1167C-1 (Note 4)	$0^{\circ}C$ to $70^{\circ}C$
LT1167AI/LT1167I/	
LT1167AI-1/LT1167I-1	$-40^{\circ}C$ to $85^{\circ}C$
Storage Temperature Range.....	$-65^{\circ}C$ to $150^{\circ}C$
Lead Temperature (Soldering, 10 sec)	$300^{\circ}C$

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT1167ACN8#PBF	LT1167ACN8#TRPBF	LT1167AC	8-Lead PDIP	$0^{\circ}C$ to $70^{\circ}C$
LT1167ACS8#PBF	LT1167ACS8#TRPBF	1167A	8-Lead Plastic SO	$0^{\circ}C$ to $70^{\circ}C$
LT1167AIN8#PBF	LT1167AIN8#TRPBF	LT1167AI	8-Lead PDIP	$-40^{\circ}C$ to $85^{\circ}C$
LT1167AIS8#PBF	LT1167AIS8#TRPBF	1167AI	8-Lead Plastic SO	$-40^{\circ}C$ to $85^{\circ}C$
LT1167CN8#PBF	LT1167CN8#TRPBF	LT1167C	8-Lead PDIP	$0^{\circ}C$ to $70^{\circ}C$
LT1167CS8#PBF	LT1167CS8#TRPBF	1167	8-Lead Plastic SO	$0^{\circ}C$ to $70^{\circ}C$
LT1167IN8#PBF	LT1167IN8#TRPBF	LT1167I	8-Lead PDIP	$-40^{\circ}C$ to $85^{\circ}C$
LT1167IS8#PBF	LT1167IS8#TRPBF	1167I	8-Lead Plastic SO	$-40^{\circ}C$ to $85^{\circ}C$
LT1167CS8-1#PBF	LT1167CS8-1#TRPBF	11671	8-Lead Plastic SO	$0^{\circ}C$ to $70^{\circ}C$
LT1167IS8-1#PBF	LT1167IS8-1#TRPBF	11671	8-Lead Plastic SO	$-40^{\circ}C$ to $85^{\circ}C$
LT1167ACS8-1#PBF	LT1167ACS8-1#TRPBF	11671	8-Lead Plastic SO	$0^{\circ}C$ to $70^{\circ}C$
LT1167AIS8-1#PBF	LT1167AIS8-1#TRPBF	11671	8-Lead Plastic SO	$-40^{\circ}C$ to $85^{\circ}C$
LEAD BASED FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT1167ACN8	LT1167ACN8#TR	LT1167AC	8-Lead PDIP	$0^{\circ}C$ to $70^{\circ}C$
LT1167ACS8	LT1167ACS8#TR	1167A	8-Lead Plastic SO	$0^{\circ}C$ to $70^{\circ}C$
LT1167AIN8	LT1167AIN8#TR	LT1167AI	8-Lead PDIP	$-40^{\circ}C$ to $85^{\circ}C$
LT1167AIS8	LT1167AIS8#TR	1167AI	8-Lead Plastic SO	$-40^{\circ}C$ to $85^{\circ}C$
LT1167CN8	LT1167CN8#TR	LT1167C	8-Lead PDIP	$0^{\circ}C$ to $70^{\circ}C$
LT1167CS8	LT1167CS8#TR	1167	8-Lead Plastic SO	$0^{\circ}C$ to $70^{\circ}C$
LT1167IN8	LT1167IN8#TR	LT1167I	8-Lead PDIP	$-40^{\circ}C$ to $85^{\circ}C$
LT1167IS8	LT1167IS8#TR	1167I	8-Lead Plastic SO	$-40^{\circ}C$ to $85^{\circ}C$

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandree/>

1167fc

ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$, $V_{CM} = 0V$, $T_A = 25^\circ C$, $R_L = 2k$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (NOTE 7)	LT1167AC/LTC1167AI LT1167AC-1/LTC1167AI-1			LT1167C/LTC1167I LT1167C-1/LTC1167I-1			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
G	Gain Range	$G = 1 + (49.4k/R_G)$	1		10k	1		10k	
	Gain Error	$G = 1$		0.008	0.02		0.015	0.03	%
		$G = 10$ (Note 2)		0.010	0.08		0.020	0.10	%
		$G = 100$ (Note 2)		0.025	0.08		0.030	0.10	%
		$G = 1000$ (Note 2)		0.049	0.10		0.040	0.10	%
Gain Nonlinearity (Note 5)	$V_O = \pm 10V$, $G = 1$		1	6		1.5	10	ppm	
	$V_O = \pm 10V$, $G = 10$ and 100		2	10		3	15	ppm	
	$V_O = \pm 10V$, $G = 1000$		15	40		20	60	ppm	
	$V_O = \pm 10V$, $G = 1$, $R_L = 600$		5	12		6	15	ppm	
	$V_O = \pm 10V$, $G = 10$ and 100, $R_L = 600$		6	15		7	20	ppm	
	$V_O = \pm 10V$, $G = 1000$, $R_L = 600$		20	65		25	80	ppm	
V _{OST}	Total Input Referred Offset Voltage	V _{OST} = V _{OSI} + V _{OSO} /G							
V _{OSI}	Input Offset Voltage	$G = 1000$, V _S = ±5V to ±15V		15	40		20	60	μV
V _{OSO}	Output Offset Voltage	$G = 1$, V _S = ±5V to ±15V		40	200		50	300	μV
I _{OS}	Input Offset Current			90	320		100	450	pA
I _B	Input Bias Current			50	350		80	500	pA
e _n	Input Noise Voltage (Note 8)	0.1Hz to 10Hz, $G = 1$ 0.1Hz to 10Hz, $G = 10$ 0.1Hz to 10Hz, $G = 100$ and 1000		2.00 0.50 0.28			2.00 0.50 0.28		μV _{P-P} μV _{P-P} μV _{P-P}
Total RTI Noise = $\sqrt{e_{ni}^2 + (e_{no}/G)^2}$ (Note 8)									
e _{ni}	Input Noise Voltage Density (Note 8)	f ₀ = 1kHz		7.5	12		7.5	12	nV/√Hz
e _{no}	Output Noise Voltage Density (Note 8)	f ₀ = 1kHz (Note 3)		67	90		67	90	nV/√Hz
i _n	Input Noise Current	f ₀ = 0.1Hz to 10Hz		10			10		pA _{P-P}
	Input Noise Current Densty	f ₀ = 10Hz		124			124		fA/√Hz
R _{IN}	Input Resistance	V _{IN} = ±10V	200	1000		200	1000		GΩ
C _{IN(DIFF)}	Differential Input Capacitance	f ₀ = 100kHz		1.6			1.6		pF
C _{IN(CM)}	Common Mode Input Capacitance	f ₀ = 100kHz		1.6			1.6		pF
V _{CM}	Input Voltage Range	$G = 1$, Other Input Grounded V _S = ±2.3V to ±5V V _S = ±5V to ±18V	-V _S +1.9 -V _S +1.9		+V _S -1.2 +V _S -1.4	-V _S +1.9 -V _S +1.9		+V _S -1.2 +V _S -1.4	V V
CMRR	Common Mode Rejection Ratio	1k Source Imbalance, V _{CM} = 0V to ±10V							
		$G = 1$	90	95		85	95		dB
		$G = 10$	106	115		100	115		dB
		$G = 100$	120	125		110	125		dB
		$G = 1000$	126	140		120	140		dB
PSRR	Power Supply Rejection Ratio	V _S = ±2.3V to ±18V							
		$G = 1$	105	120		100	120		dB
		$G = 10$	125	135		120	135		dB
		$G = 100$	131	140		126	140		dB
		$G = 1000$	135	150		130	150		dB
I _S	Supply Current	V _S = ±2.3V to ±18V		0.9	1.3		0.9	1.3	mA
V _{OUT}	Output Voltage Swing	R _L = 10k V _S = ±2.3V to ±5V V _S = ±5V to ±18V	-V _S +1.1 -V _S +1.2		+V _S -1.2 +V _S -1.3	-V _S +1.1 -V _S +1.2		+V _S -1.2 +V _S -1.3	V V

ELECTRICAL CHARACTERISTICS

 $V_S = \pm 15V$, $V_{CM} = 0V$, $T_A = 25^\circ C$, $R_L = 2k$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (NOTE 7)	LT1167AC/LTC1167AI LT1167AC-1/LTC1167AI-1			LT1167C/LTC1167I LT1167C-1/LTC1167I-1			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{OUT}	Output Current		20	27		20	27		mA
BW	Bandwidth	$G = 1$		1000			1000		kHz
		$G = 10$		800			800		kHz
		$G = 100$		120			120		kHz
		$G = 1000$		12			12		kHz
SR	Slew Rate	$G = 1$, $V_{OUT} = \pm 10V$	0.75	1.2		0.75	1.2		V/ μs
	Settling Time to 0.01%	10V Step							
		$G = 1$ to 100		14			14		μs
		$G = 1000$		130			130		μs
R_{REFIN}	Reference Input Resistance			20			20		k Ω
I_{REFIN}	Reference Input Current	$V_{REF} = 0V$		50			50		μA
V_{REF}	Reference Voltage Range		$-V_S + 1.6$		$+V_S - 1.6$	$-V_S + 1.6$		$+V_S - 1.6$	V
A_{VREF}	Reference Gain to Output			1 ± 0.0001			1 ± 0.0001		

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ C$.

$V_S = \pm 15V$, $V_{CM} = 0V$, $0^\circ C \leq T_A \leq 70^\circ C$, $R_L = 2k$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (NOTE 7)		LT1167AC/LT1167AC-1			LT1167C/LT1167C-1			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
	Gain Error	$G = 1$	●		0.01	0.03		0.012	0.04	%
		$G = 10$ (Note 2)	●		0.08	0.30		0.100	0.33	%
		$G = 100$ (Note 2)	●		0.09	0.30		0.120	0.33	%
		$G = 1000$ (Note 2)	●		0.14	0.33		0.140	0.35	%
	Gain Nonlinearity	$V_{OUT} = \pm 10V$, $G = 1$	●		1.5	10		3	15	ppm
		$V_{OUT} = \pm 10V$, $G = 10$ and 100	●		3	15		4	20	ppm
		$V_{OUT} = \pm 10V$, $G = 1000$	●		20	60		25	80	ppm
G/T	Gain vs Temperature	$G < 1000$ (Note 2)	●		20	50		20	50	ppm/ $^\circ C$
V_{OST}	Total Input Referred Offset Voltage	$V_{OST} = V_{OSI} + V_{OSO}/G$								
V_{OSI}	Input Offset Voltage	$V_S = \pm 5V$ to $\pm 15V$	●		18	60		23	80	μV
V_{OSIH}	Input Offset Voltage Hysteresis	(Notes 3, 6)			3.0			3.0		μV
V_{OSO}	Output Offset Voltage	$V_S = \pm 5V$ to $\pm 15V$	●		60	380		70	500	μV
V_{OSOH}	Output Offset Voltage Hysteresis	(Notes 3, 6)			30			30		μV
V_{OSI}/T	Input Offset Drift (Note 8)	(Note 3)	●		0.05	0.3		0.06	0.4	$\mu V/^\circ C$
V_{OSO}/T	Output Offset Drift	(Note 3)	●		0.7	3		0.8	4	$\mu V/^\circ C$
I_{OS}	Input Offset Current		●		100	400		120	550	pA
I_{OS}/T	Input Offset Current Drift		●		0.3			0.4		pA/ $^\circ C$
I_B	Input Bias Current		●		75	450		105	600	pA
I_B/T	Input Bias Current Drift		●		0.4			0.4		pA/ $^\circ C$
V_{CM}	Input Voltage Range	$G = 1$, Other Input Grounded								
		$V_S = \pm 2.3V$ to $\pm 5V$	●	$-V_S + 2.1$		$+V_S - 1.3$	$-V_S + 2.1$		$+V_S - 1.3$	V
		$V_S = \pm 5V$ to $\pm 18V$	●	$-V_S + 2.1$		$+V_S - 1.4$	$-V_S + 2.1$		$+V_S - 1.4$	V
CMRR	Common Mode Rejection Ratio	1k Source Imbalance, $V_{CM} = 0V$ to $\pm 10V$								
		$G = 1$	●		88	92		83	92	dB
		$G = 10$	●		100	110		97	110	dB
		$G = 100$	●		115	120		113	120	dB
		$G = 1000$	●		117	135		114	135	dB

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $R_L = 2\text{k}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (NOTE 7)		LT1167AC/LT1167AC-1			LT1167C/LT1167C-1			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.3\text{V to } \pm 18\text{V}$	●	103	115		98	115		dB
		$G = 1$	●	123	130		118	130		dB
		$G = 10$	●	127	135		124	135		dB
		$G = 100$	●	129	145		126	145		dB
I_S	Supply Current	$V_S = \pm 2.3\text{V to } \pm 18\text{V}$	●		1.0	1.5		1.0	1.5	mA
V_{OUT}	Output Voltage Swing	$R_L = 10\text{k}$								
		$V_S = \pm 2.3\text{V to } \pm 5\text{V}$	●	$-V_S+1.4$		$+V_S-1.3$	$-V_S+1.4$		$+V_S-1.3$	V
		$V_S = \pm 5\text{V to } \pm 18\text{V}$	●	$-V_S+1.6$		$+V_S-1.5$	$-V_S+1.6$		$+V_S-1.5$	V
I_{OUT}	Output Current		●	16	21		16	21		mA
SR	Slew Rate	$G = 1$, $V_{OUT} = \pm 10\text{V}$	●	0.65	1.1		0.65	1.1		V/ μs
V_{REF}	REF Voltage Range	(Note 3)	●	$-V_S+1.6$		$+V_S-1.6$	$-V_S+1.6$		$+V_S-1.6$	V

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$, $R_L = 2\text{k}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (NOTE 7)		LT1167AI/LT1167AI-1			LT1167I/LT1167I-1			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
	Gain Error	$G = 1$	●		0.014	0.04		0.015	0.05	%
		$G = 10$ (Note 2)	●		0.130	0.40		0.140	0.42	%
		$G = 100$ (Note 2)	●		0.140	0.40		0.150	0.42	%
		$G = 1000$ (Note 2)	●		0.160	0.40		0.180	0.45	%
G_N	Gain Nonlinearity (Notes 2, 4)	$V_O = \pm 10\text{V}$, $G = 1$	●		2	15		3	20	ppm
		$V_O = \pm 10\text{V}$, $G = 10$ and 100	●		5	20		6	30	ppm
		$V_O = \pm 10\text{V}$, $G = 1000$	●		26	70		30	100	ppm
G/T	Gain vs Temperature	$G < 1000$ (Note 2)	●		20	50		20	50	ppm/ $^\circ\text{C}$
V_{OST}	Total Input Referred Offset Voltage	$V_{OST} = V_{OSI} + V_{OSO}/G$								
V_{OSI}	Input Offset Voltage		●		20	75		25	100	μV
V_{OSIH}	Input Offset Voltage Hysteresis	(Notes 3, 6)			3.0			3.0		μV
V_{OSO}	Output Offset Voltage		●		180	500		200	600	μV
V_{OSOH}	Output Offset Voltage Hysteresis	(Notes 3, 6)			30			30		μV
V_{OSI}/T	Input Offset Drift (Note 8)	(Note 3)	●		0.05	0.3		0.06	0.4	$\mu\text{V}/^\circ\text{C}$
V_{OSO}/T	Output Offset Drift	(Note 3)	●		0.8	5		1	6	$\mu\text{V}/^\circ\text{C}$
I_{OS}	Input Offset Current		●		110	550		120	700	pA
I_{OS}/T	Input Offset Current Drift		●		0.3			0.3		pA/ $^\circ\text{C}$
I_B	Input Bias Current		●		180	600		220	800	pA
I_B/T	Input Bias Current Drift		●		0.5			0.6		pA/ $^\circ\text{C}$
V_{CM}	Input Voltage Range	$V_S = \pm 2.3\text{V to } \pm 5\text{V}$	●	$-V_S+2.1$		$+V_S-1.3$	$-V_S+2.1$		$+V_S-1.3$	V
		$V_S = \pm 5\text{V to } \pm 18\text{V}$	●	$-V_S+2.1$		$+V_S-1.4$	$-V_S+2.1$		$+V_S-1.4$	V
CMRR	Common Mode Rejection Ratio	1k Source Imbalance, $V_{CM} = 0\text{V to } \pm 10\text{V}$								
		$G = 1$	●	86	90		81	90		dB
		$G = 10$	●	98	105		95	105		dB
		$G = 100$	●	114	118		112	118		dB
		$G = 1000$	●	116	133		112	133		dB

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $R_L = 2\text{k}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS (NOTE 7)		LT1167AI/LT1167AI-1			LT1167I/LT1167I-1			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2.3\text{V to } \pm 18\text{V}$	●	100	112		95	112		dB
		$G = 1$	●	120	125		115	125		dB
		$G = 10$	●	125	132		120	132		dB
		$G = 1000$	●	128	140		125	140		dB
I_S	Supply Current		●		1.1	1.6		1.1	1.6	mA
V_{OUT}	Output Voltage Swing	$V_S = \pm 2.3\text{V to } \pm 5\text{V}$	●	$-V_S + 1.4$		$+V_S - 1.3$	$-V_S + 1.4$		$+V_S - 1.3$	V
		$V_S = \pm 5\text{V to } \pm 18\text{V}$	●	$-V_S + 1.6$		$+V_S - 1.5$	$-V_S + 1.6$		$+V_S - 1.5$	V
I_{OUT}	Output Current		●	15	20		15	20		mA
SR	Slew Rate	$G = 1$, $V_{OUT} = \pm 10\text{V}$	●	0.55	0.95		0.55	0.95		V/ μs
V_{REF}	REF Voltage Range	(Note 3)	●	$-V_S + 1.6$		$+V_S - 1.6$	$-V_S + 1.6$		$+V_S - 1.6$	V

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: Does not include the effect of the external gain resistor R_G .

Note 3: This parameter is not 100% tested.

Note 4: The LT1167AC/LT1167C/LT1167AC-1/LT1167C-1 are designed, characterized and expected to meet the industrial temperature limits, but are not tested at -40°C and 85°C . I-grade parts are guaranteed.

Note 5: This parameter is measured in a high speed automatic tester that does not measure the thermal effects with longer time constants. The magnitude of these thermal effects are dependent on the package used, heat sinking and air flow conditions.

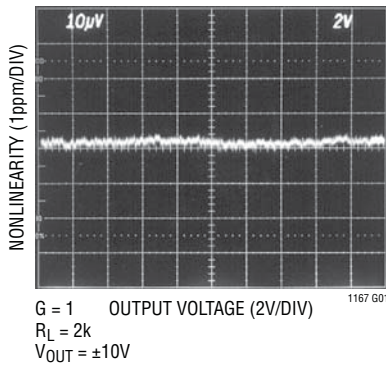
Note 6: Hysteresis in offset voltage is created by package stress that differs depending on whether the IC was previously at a higher or lower temperature. Offset voltage hysteresis is always measured at 25°C , but the IC is cycled to 85°C I-grade (or 70°C C-grade) or -40°C I-grade (0°C C-grade) before successive measurement. 60% of the parts will pass the typical limit on the data sheet.

Note 7: Typical parameters are defined as the 60% of the yield parameter distribution.

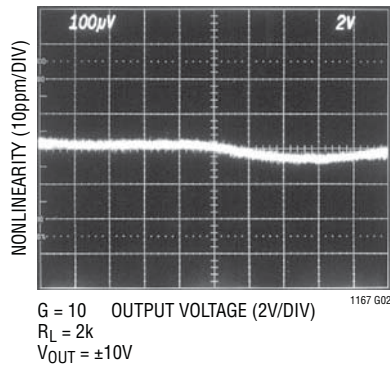
Note 8: Referred to input.

TYPICAL PERFORMANCE CHARACTERISTICS

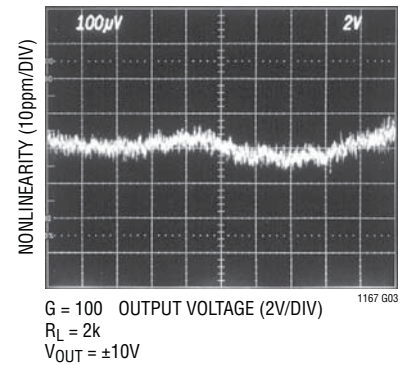
Gain Nonlinearity, $G = 1$



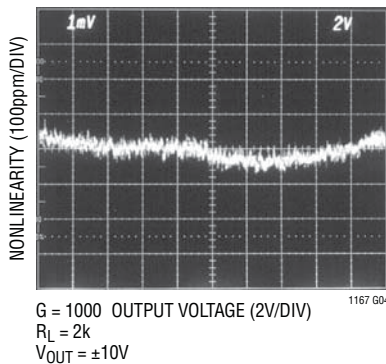
Gain Nonlinearity, $G = 10$



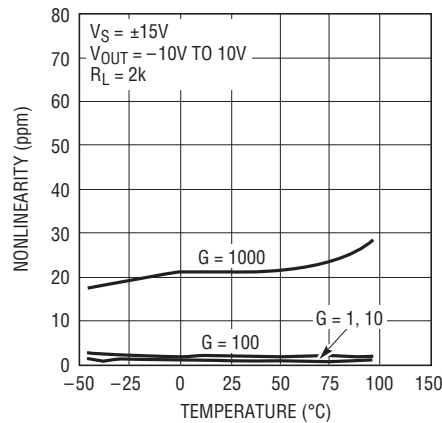
Gain Nonlinearity, $G = 100$



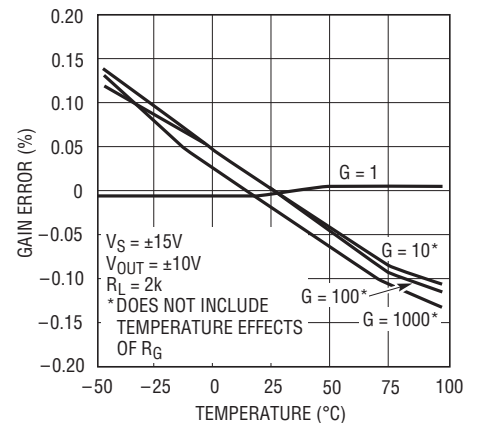
Gain Nonlinearity, $G = 1000$



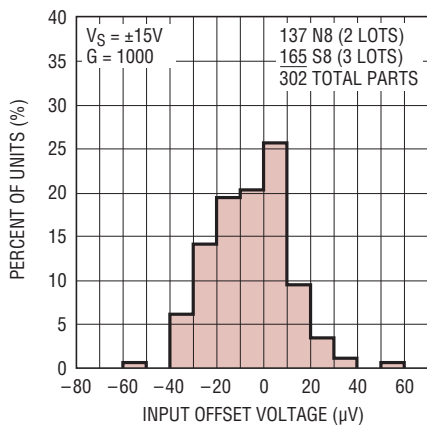
Gain Nonlinearity vs Temperature



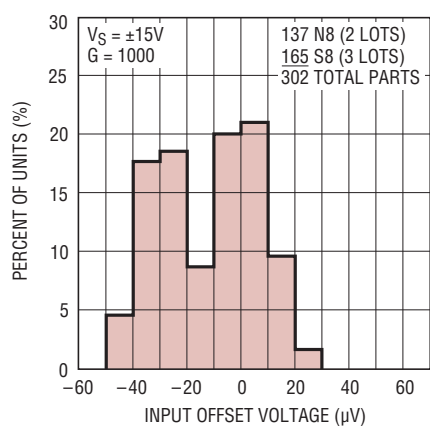
Gain Error vs Temperature



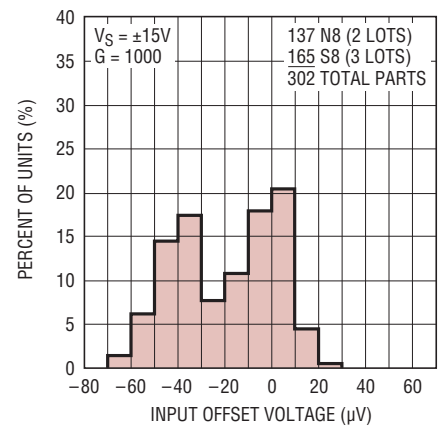
Distribution of Input Offset Voltage, $T_A = -40^\circ\text{C}$



Distribution of Input Offset Voltage, $T_A = 25^\circ\text{C}$

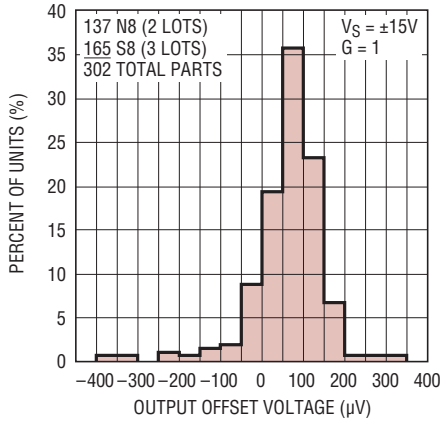


Distribution of Input Offset Voltage, $T_A = 85^\circ\text{C}$



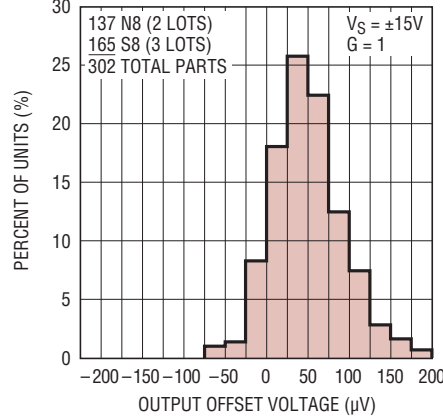
TYPICAL PERFORMANCE CHARACTERISTICS

Distribution of Output Offset Voltage, $T_A = -40^\circ\text{C}$



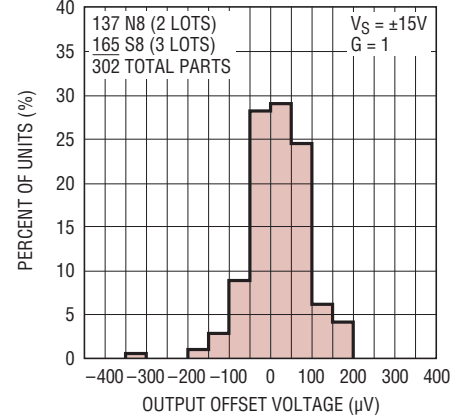
1167 G43

Distribution of Output Offset Voltage, $T_A = 25^\circ\text{C}$



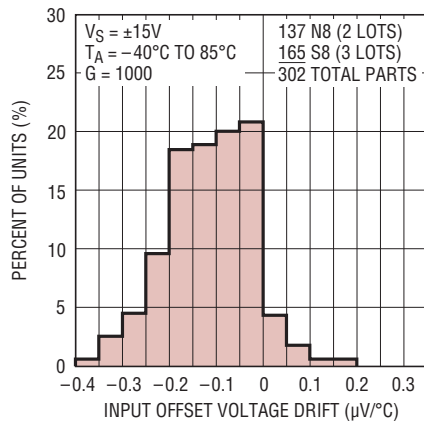
1167 G44

Distribution of Output Offset Voltage, $T_A = 85^\circ\text{C}$



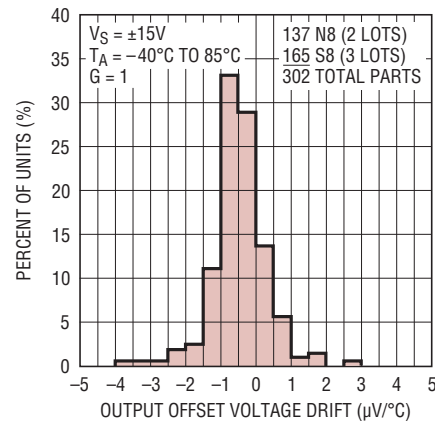
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Distribution of Input Offset Voltage Drift



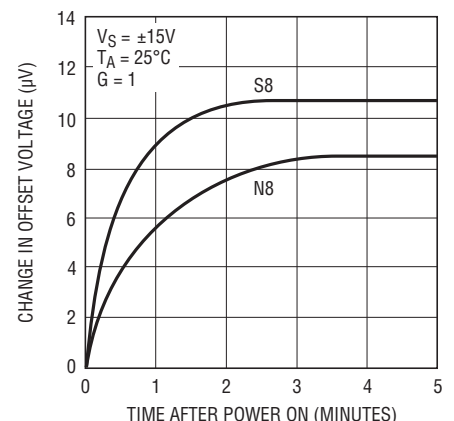
1167 G46

Distribution of Output Offset Voltage Drift



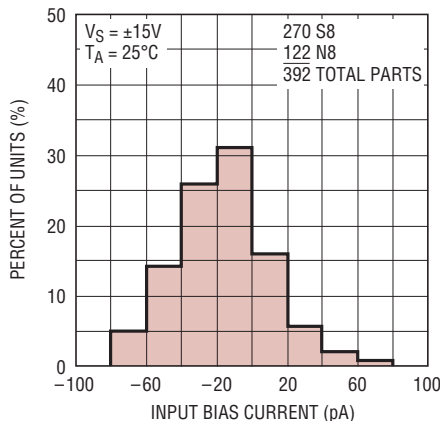
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Warm-Up Drift



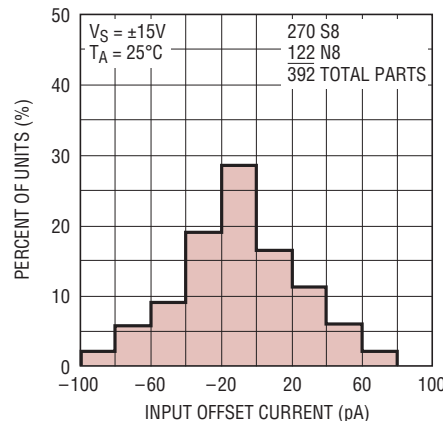
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Input Bias Current



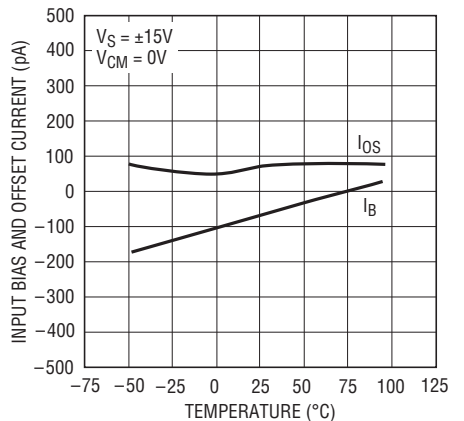
1167 G10

Input Offset Current



1167 G11

Input Bias and Offset Current vs Temperature

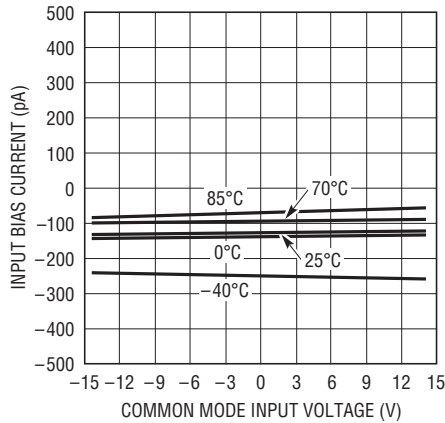


1167 G12

1167fc

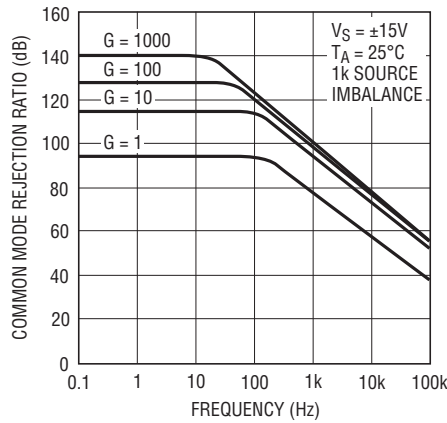
TYPICAL PERFORMANCE CHARACTERISTICS

Input Bias Current vs Common Mode Input Voltage



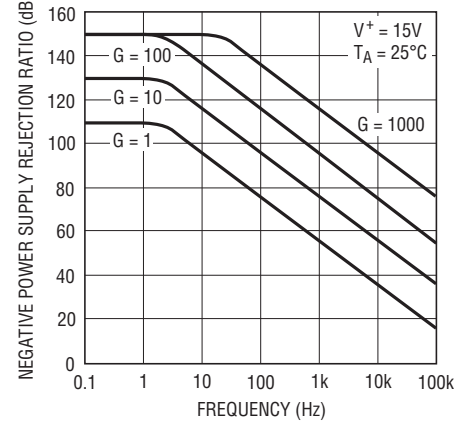
1167 G13

Common Mode Rejection Ratio vs Frequency



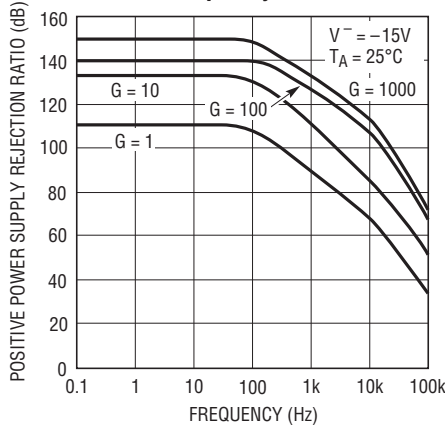
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Negative Power Supply Rejection Ratio vs Frequency



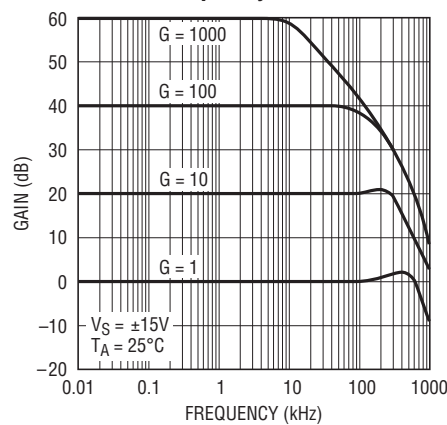
1167 G15

Positive Power Supply Rejection Ratio vs Frequency



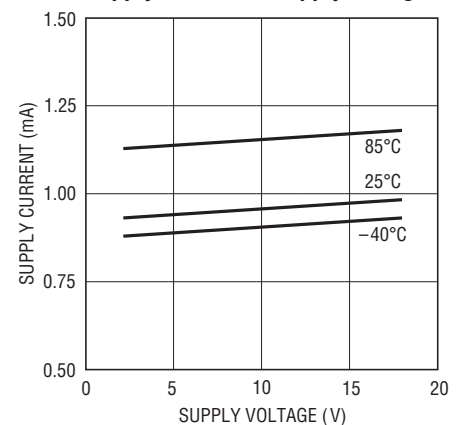
1167 G16

Gain vs Frequency



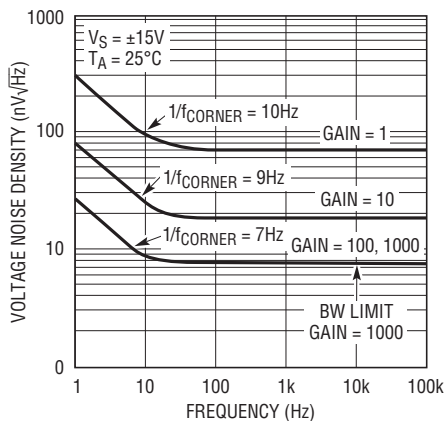
1167 G17

Supply Current vs Supply Voltage



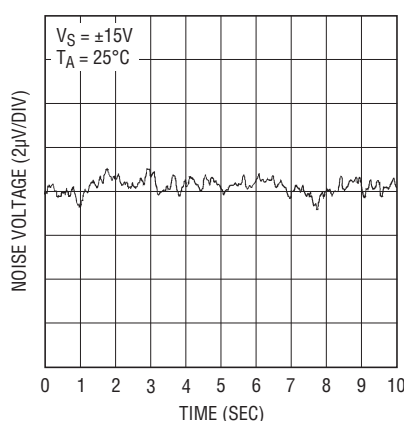
1167 G18

Voltage Noise Density vs Frequency



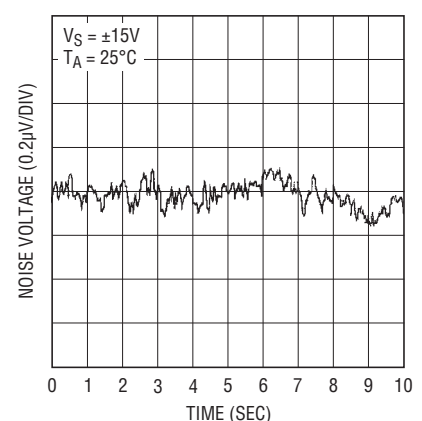
1167 G19

0.1Hz to 10Hz Noise Voltage, G = 1



1167 G20

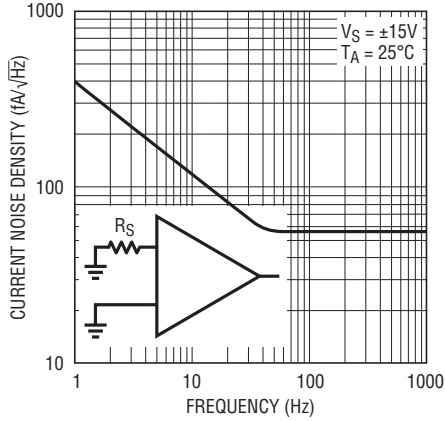
0.1Hz to 10Hz Noise Voltage, Referred to Input, G = 1000



1167 G21

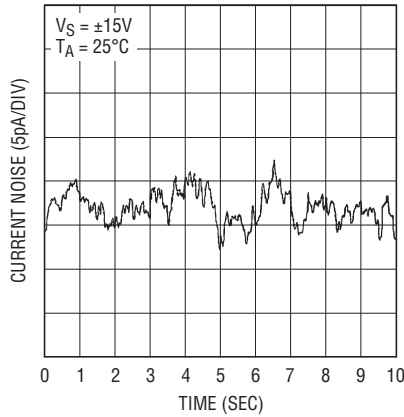
TYPICAL PERFORMANCE CHARACTERISTICS

Current Noise Density vs Frequency



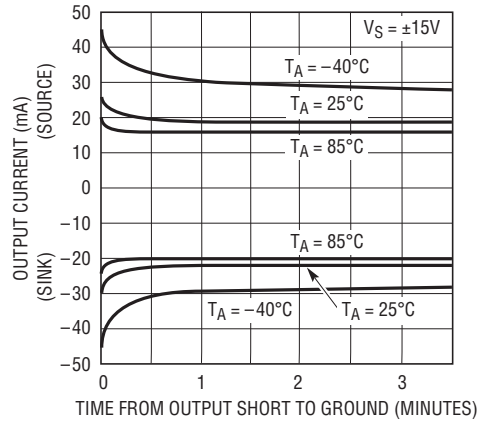
1167 G22

0.1Hz to 10Hz Current Noise



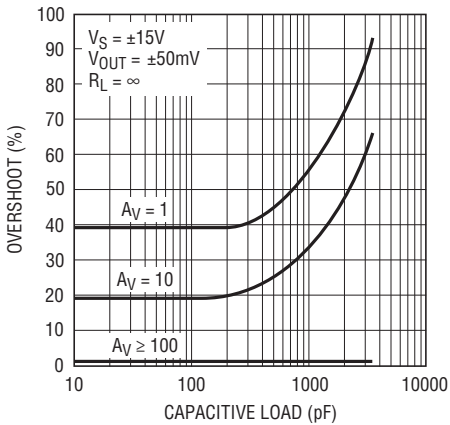
1167 G23

Short-Circuit Current vs Time



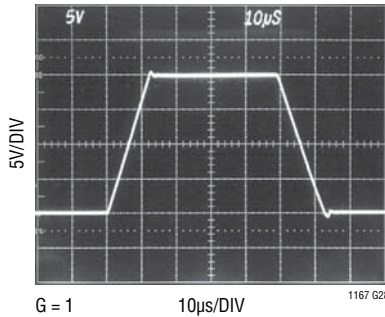
1167 G24

Overshoot vs Capacitive Load



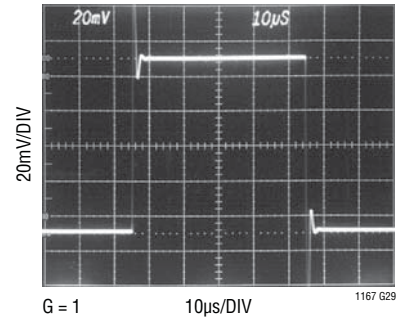
1167 G25

Large-Signal Transient Response



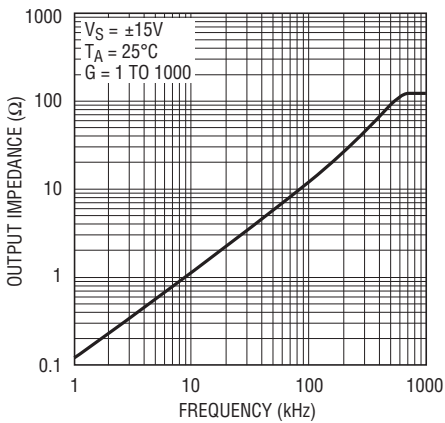
1167 G28

Small-Signal Transient Response



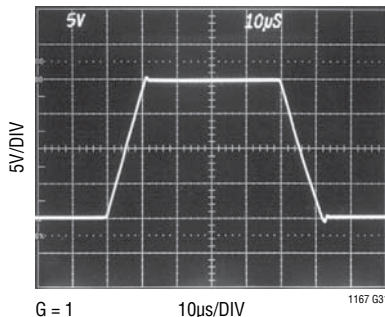
1167 G29

Output Impedance vs Frequency



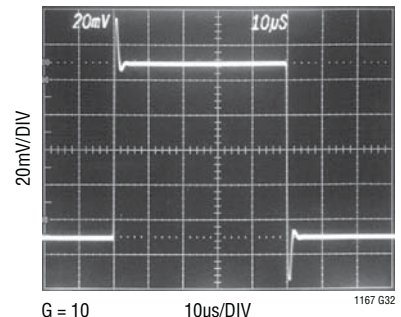
1167 G26

Large-Signal Transient Response



1167 G31

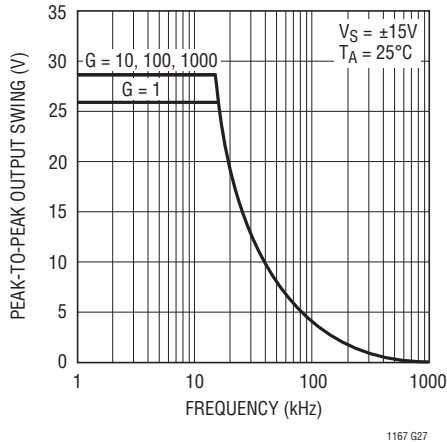
Small-Signal Transient Response



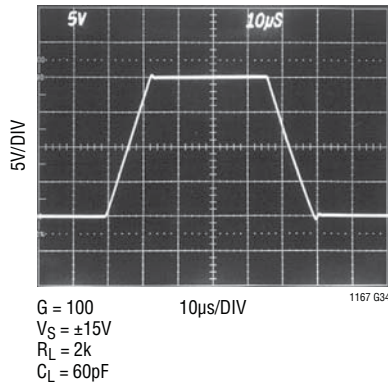
1167 G32

TYPICAL PERFORMANCE CHARACTERISTICS

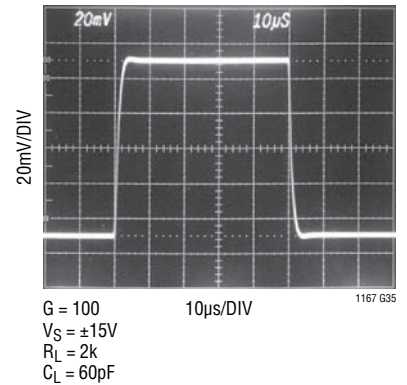
Undistorted Output Swing vs Frequency



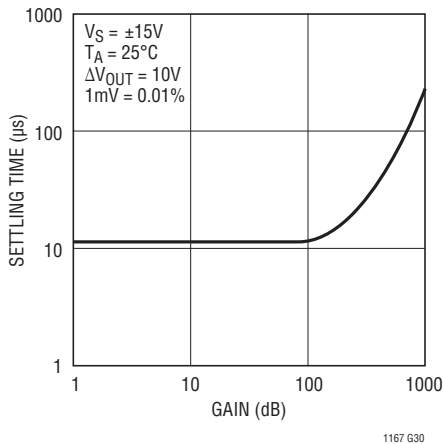
Large-Signal Transient Response



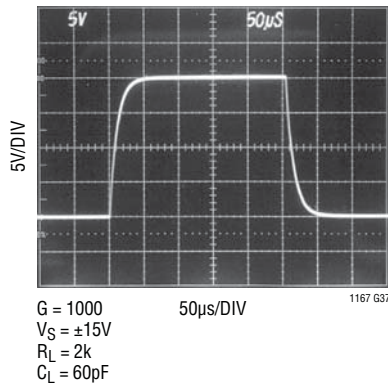
Small-Signal Transient Response



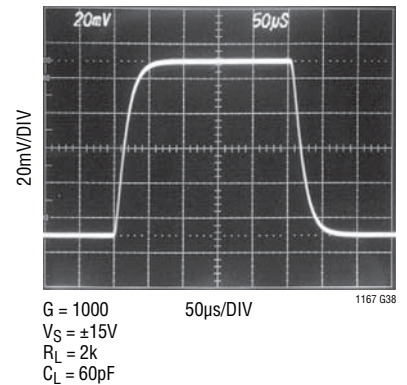
Settling Time vs Gain



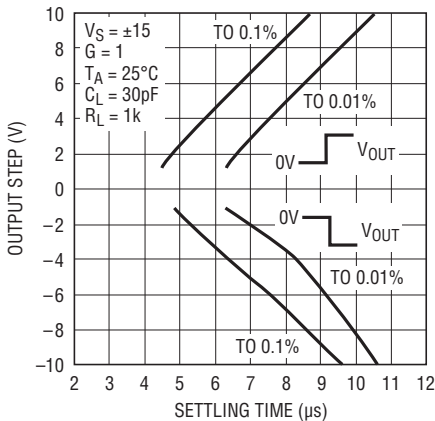
Large-Signal Transient Response



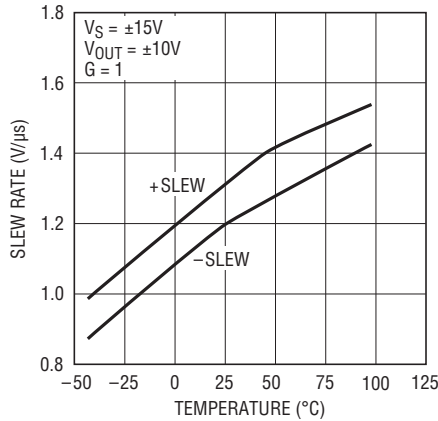
Small-Signal Transient Response



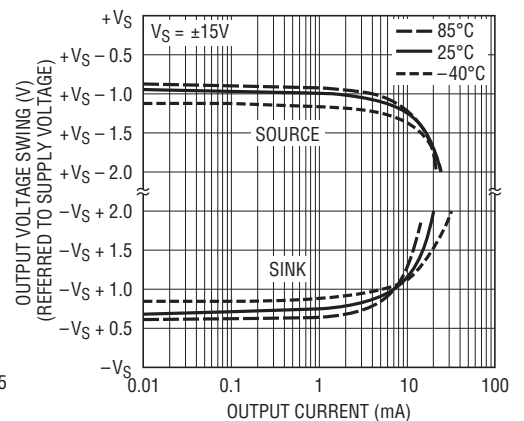
Settling Time vs Step Size



Slew Rate vs Temperature



Output Voltage Swing vs Load Current



BLOCK DIAGRAM

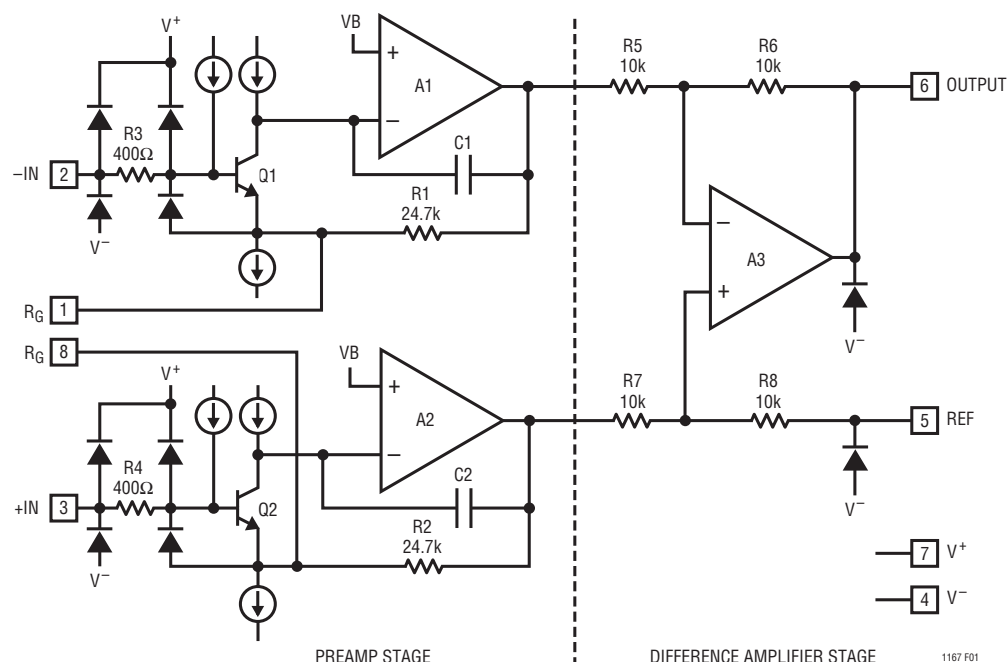


Figure 1. Block Diagram

THEORY OF OPERATION

The LT1167 is a modified version of the three op amp instrumentation amplifier. Laser trimming and monolithic construction allow tight matching and tracking of circuit parameters over the specified temperature range. Refer to the block diagram (Figure 1) to understand the following circuit description. The collector currents in Q1 and Q2 are trimmed to minimize offset voltage drift, thus assuring a high level of performance. R1 and R2 are trimmed to an absolute value of 24.7k to assure that the gain can be set accurately (0.05% at $G = 100$) with only one external resistor R_G . The value of R_G determines the transconductance of the preamp stage. As R_G is reduced for larger programmed gains, the transconductance of the input preamp stage increases to that of the input transistors Q1 and Q2. This increases the open-loop gain when the programmed gain is increased, reducing the input referred gain related errors and noise. The input voltage noise at gains greater than 50 is determined only by Q1 and Q2. At lower gains the noise of the difference amplifier and preamp gain setting resistors increase the noise. The gain bandwidth product is determined by C1, C2 and the preamp transconductance which increases

with programmed gain. Therefore, the bandwidth does not drop proportionally to gain.

The input transistors Q1 and Q2 offer excellent matching, which is inherent in NPN bipolar transistors, as well as picoampere input bias current due to superbeta processing. The collector currents in Q1 and Q2 are held constant due to the feedback through the Q1-A1-R1 loop and Q2-A2-R2 loop which in turn impresses the differential input voltage across the external gain set resistor R_G . Since the current that flows through R_G also flows through R1 and R2, the ratios provide a gained-up differential voltage, $G = (R1 + R2)/R_G$, to the unity-gain difference amplifier A3. The common mode voltage is removed by A3, resulting in a single-ended output voltage referenced to the voltage on the REF pin. The resulting gain equation is:

$$V_{OUT} - V_{REF} = G(V_{IN}^{+} - V_{IN}^{-})$$

where:

$$G = (49.4k\Omega/R_G) + 1$$

solving for the gain set resistor gives:

$$R_G = 49.4k\Omega/(G - 1)$$

THEORY OF OPERATION

Input and Output Offset Voltage

The offset voltage of the LT1167 has two components: the output offset and the input offset. The total offset voltage referred to the input (RTI) is found by dividing the output offset by the programmed gain (G) and adding it to the input offset. At high gains the input offset voltage dominates, whereas at low gains the output offset voltage dominates. The total offset voltage is:

$$\begin{aligned} \text{Total input offset voltage (RTI)} \\ &= \text{input offset} + (\text{output offset}/G) \end{aligned}$$

$$\begin{aligned} \text{Total output offset voltage (RTO)} \\ &= (\text{input offset} \cdot G) + \text{output offset} \end{aligned}$$

Reference Terminal

The reference terminal is one end of one of the four 10k resistors around the difference amplifier. The output voltage of the LT1167 (Pin 6) is referenced to the voltage on the reference terminal (Pin 5). Resistance in series with the REF pin must be minimized for best common mode rejection. For example, a 2Ω resistance from the REF pin to ground will not only increase the gain error by 0.02% but will lower the CMRR to 80dB.

Single Supply Operation

For single supply operation, the REF pin can be at the same potential as the negative supply (Pin 4) provided the output of the instrumentation amplifier remains inside the specified operating range and that one of the inputs is at least 2.5V above ground. The barometer application on the front page of this data sheet is an example that satisfies these conditions. The resistance R_b from the bridge transducer to ground sets the operating current for the bridge and also has the effect of raising the input common mode voltage. The output of the LT1167 is always inside the specified range since the barometric pressure rarely goes low enough to cause the output to rail (30.00 inches of Hg corresponds to 3.000V). For applications that require the output to swing at or below the REF potential, the voltage on the REF pin can be level shifted. An op amp is used to buffer the voltage on the REF pin since a parasitic series resistance will degrade the CMRR. The application in the back of this data sheet, Four Digit Pressure Sensor, is an example.

Output Offset Trimming

The LT1167 is laser trimmed for low offset voltage so that no external offset trimming is required for most applications. In the event that the offset needs to be adjusted, the circuit in Figure 2 is an example of an optional offset adjust circuit. The op amp buffer provides a low impedance to the REF pin where resistance must be kept to minimum for best CMRR and lowest gain error.

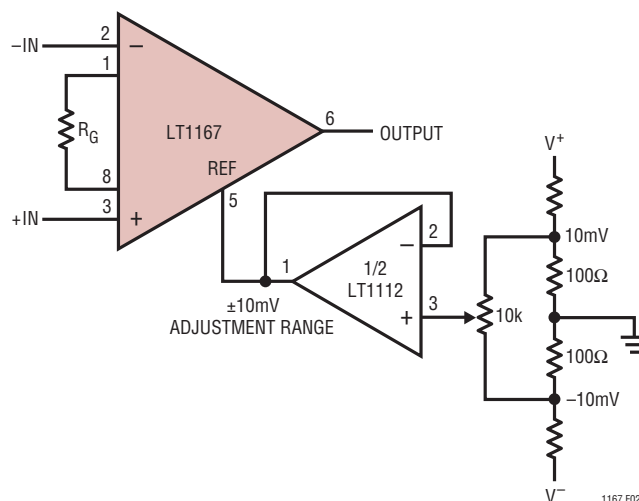


Figure 2. Optional Trimming of Output Offset Voltage

Input Bias Current Return Path

The low input bias current of the LT1167 (350pA) and the high input impedance (200GΩ) allow the use of high impedance sources without introducing additional offset voltage errors, even when the full common mode range is required. However, a path must be provided for the input bias currents of both inputs when a purely differential signal is being amplified. Without this path the inputs will float to either rail and exceed the input common mode range of the LT1167, resulting in a saturated input stage. Figure 3 shows three examples of an input bias current path. The first example is of a purely differential signal source with a 10kΩ input current path to ground. Since the impedance of the signal source is low, only one resistor is needed. Two matching resistors are needed for higher impedance signal sources as shown in the second example. Balancing the input impedance improves both common mode rejection and DC offset. The need for input resistors is eliminated if a center tap is present as shown in the third example.

1167fc

THEORY OF OPERATION

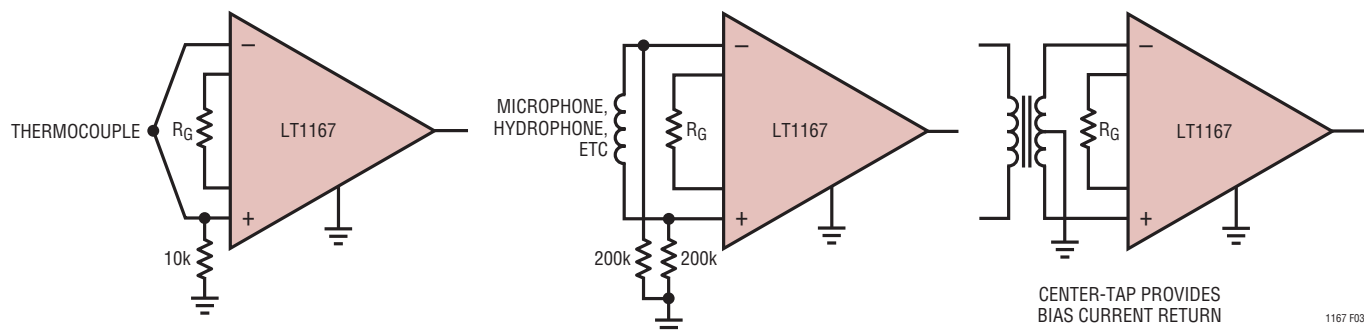


Figure 3. Providing an Input Common Mode Current Path

APPLICATIONS INFORMATION

The LT1167 is a low power precision instrumentation amplifier that requires only one external resistor to accurately set the gain anywhere from 1 to 1000. The output can handle capacitive loads up to 1000pF in any gain configuration and the inputs are protected against ESD strikes up to 13kV (human body).

Input Current at High Common Mode Voltage

When operating within the specified input common mode range, both the LT1167 and LT1167-1 operate as shown in the Input Bias Current vs Common Mode Input Voltage graph shown in the Typical Performance Characteristics. If however the inputs are within approximately 0.8V of the positive supply, the LT1167 input current will increase to approximately $-1\mu\text{A}$ to $-3\mu\text{A}$. If the impedance of the circuit driving the LT1167 inputs is sufficiently high (e.g., $10\text{M}\Omega$ when $+V_S = 15\text{V}$), this increased input current can pull the input voltage sufficiently high to keep the elevated input current flowing. The LT1167-1 has been modified so that the input current is typically two orders of magnitude lower under similar conditions. The LT1167-1 is recommended for new designs where input impedance is high.

Input Protection

The LT1167 can safely handle up to $\pm 20\text{mA}$ of input current in an overload condition. Adding an external 5k input resistor in series with each input allows DC input fault voltages up to $\pm 100\text{V}$ and improves the ESD immunity to 8kV (contact) and 15kV (air discharge), which is the IEC 1000-4-2 level 4 specification. If lower value input

resistors are needed, a clamp diode from the positive supply to each input will maintain the IEC 1000-4-2 specification to level 4 for both air and contact discharge. A 2N4393 drain/source to gate is a good low leakage diode for use with 1k resistors, see Figure 4. The input resistors should be carbon and not metal film or carbon film.

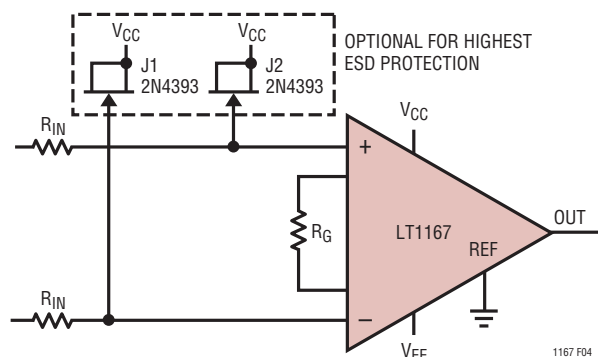


Figure 4. Input Protection

RFI Reduction

In many industrial and data acquisition applications, instrumentation amplifiers are used to accurately amplify small signals in the presence of large common mode voltages or high levels of noise. Typically, the sources of these very small signals (on the order of microvolts or millivolts) are sensors that can be a significant distance from the signal conditioning circuit. Although these sensors may be connected to signal conditioning circuitry, using shielded or unshielded twisted-pair cabling, the cabling may act as antennae, conveying very high frequency interference directly into the input stage of the LT1167.

APPLICATIONS INFORMATION

The amplitude and frequency of the interference can have an adverse effect on an instrumentation amplifier's input stage by causing an unwanted DC shift in the amplifier's input offset voltage. This well known effect is called RFI rectification and is produced when out-of-band interference is coupled (inductively, capacitively or via radiation) and rectified by the instrumentation amplifier's input transistors. These transistors act as high frequency signal detectors, in the same way diodes were used as RF envelope detectors in early radio designs. Regardless of the type of interference or the method by which it is coupled into the circuit, an out-of-band error signal appears in series with the instrumentation amplifier's inputs.

To significantly reduce the effect of these out-of-band signals on the input offset voltage of instrumentation amplifiers, simple lowpass filters can be used at the inputs. These filters should be located very close to the input pins of the circuit. An effective filter configuration is illustrated in Figure 5, where three capacitors have been added to the inputs of the LT1167. Capacitors C_{XCM1} and C_{XCM2} form lowpass filters with the external series resistors $R_{S1,2}$ to any out-of-band signal appearing on each of the input traces. Capacitor C_{XD} forms a filter to reduce any unwanted signal that would appear across the input traces. An added benefit to using C_{XD} is that the circuit's AC common mode rejection is not degraded due to common mode capacitive

imbalance. The differential mode and common mode time constants associated with the capacitors are:

$$t_{DM(LPF)} = (2)(R_S)(C_{XD})$$

$$t_{CM(LPF)} = (R_{S1,2})(C_{XCM1,2})$$

Setting the time constants requires a knowledge of the frequency, or frequencies of the interference. Once this frequency is known, the common mode time constants can be set followed by the differential mode time constant. To avoid any possibility of inadvertently affecting the signal to be processed, set the common mode time constant an order of magnitude (or more) larger than the differential mode time constant. Set the common mode time constants such that they do not degrade the LT1167's inherent AC CMR. Then the differential mode time constant can be set for the bandwidth required for the application. Setting the differential mode time constant close to the sensor's BW also minimizes any noise pickup along the leads. To avoid any possibility of common mode to differential mode signal conversion, match the common mode time constants to 1% or better. If the sensor is an RTD or a resistive strain gauge, then the series resistors $R_{S1,2}$ can be omitted, if the sensor is in proximity to the instrumentation amplifier.

“Roll Your Own”—Discrete vs Monolithic LT1167 Error Budget Analysis

The LT1167 offers performance superior to that of “roll your own” three op amp discrete designs. A typical application that amplifies and buffers a bridge transducer's differential output is shown in Figure 6. The amplifier, with its gain set to 100, amplifies a differential, full-scale output voltage of 20mV over the industrial temperature range. To make the comparison challenging, the low cost version of the LT1167 will be compared to a discrete instrumentation amp made with the A grade of one of the best precision quad op amps, the LT1114A. The LT1167C outperforms the discrete amplifier that has lower V_{OS} , lower I_B and comparable V_{OS} drift. The error budget comparison in Table 1 shows how various errors are calculated and how each error affects the total error budget. The table shows the greatest differences between the discrete solution and

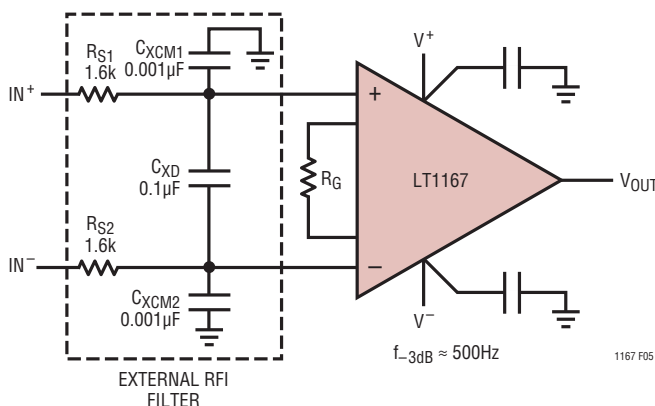


Figure 5. Adding a Simple RC Filter at the Inputs to an Instrumentation Amplifier Is Effective in Reducing Rectification of High Frequency Out-of-Band Signals

APPLICATIONS INFORMATION

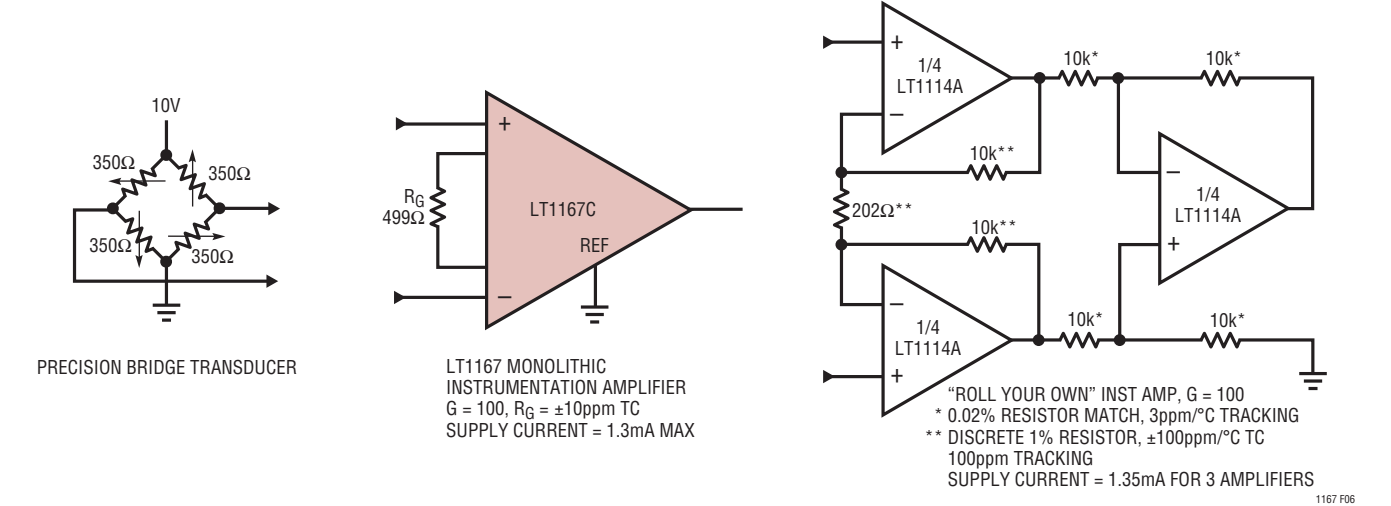


Figure 6. “Roll Your Own” vs LT1167

Table 1. “Roll Your Own” vs LT1167 Error Budget

ERROR SOURCE	LT1167C CIRCUIT CALCULATION	“ROLL YOUR OWN” CIRCUIT CALCULATION	ERROR, ppm OF FULL SCALE	
			LT1167C	“ROLL YOUR OWN”
Absolute Accuracy at T_A = 25°C				
Input Offset Voltage, μV	60μV/20mV	100μV/20mV	3000	5000
Output Offset Voltage, μV	(300μV/100)/20mV	[(60μV)(2)/100]/20mV	150	60
Input Offset Current, nA	[(450pA)(350/2)Ω]/20mV	[(450pA)(350Ω)/2]/20mV	4	4
CMR, dB	110dB→[(3.16ppm)(5V)]/20mV	[(0.02% Match)(5V)]/20mV	790	500
		Total Absolute Error	3944	5564
Drift to 85°C				
Gain Drift, ppm/°C	(50ppm + 10ppm)(60°C)	(100ppm/°C Track)(60°C)	3600	6000
Input Offset Voltage Drift, μV/°C	[(0.4μV/°C)(60°C)]/20mV	[(1.6μV/°C)(60°C)]/20mV	1200	4800
Output Offset Voltage Drift, μV/°C	[(6μV/°C)(60°C)]/100/20mV	[(1.1μV/°C)(2)(60°C)]/100/20mV	180	66
		Total Drift Error	4980	10866
Resolution				
Gain Nonlinearity, ppm of Full Scale	15ppm	10ppm	15	10
Typ 0.1Hz to 10Hz Voltage Noise, μV _{P-P}	0.28μV _{P-P} /20mV	(0.3μV _{P-P})(√2)/20mV	14	21
		Total Resolution Error	29	31
		Grand Total Error	8953	16461

G = 100, VS = ±15V
All errors are min/max and referred to input.

the LT1167 are input offset voltage and CMRR. Note that for the discrete solution, the noise voltage specification is multiplied by $\sqrt{2}$ which is the RMS sum of the uncorelated noise of the two input amplifiers. Each of the amplifier errors is referenced to a full-scale bridge differential voltage of 20mV. The common mode range of the bridge is 5V. The LT1114 data sheet provides offset voltage, offset voltage drift and offset current specifications for the matched op amp pairs used in the error-budget table. Even with an excellent matched op amp like the LT1114, the discrete solution’s total error is significantly higher than the LT1167’s

total error. The LT1167 has additional advantages over the discrete design, including lower component cost and smaller size.

Current Source

Figure 7 shows a simple, accurate, low power program-mable current source. The differential voltage across Pins 2 and 3 is mirrored across R_G . The voltage across R_G is amplified and applied across R_X , defining the out-put current. The 50μA bias current flowing from Pin 5 is buffered by the LT1464 JFET operational amplifier. This

APPLICATIONS INFORMATION

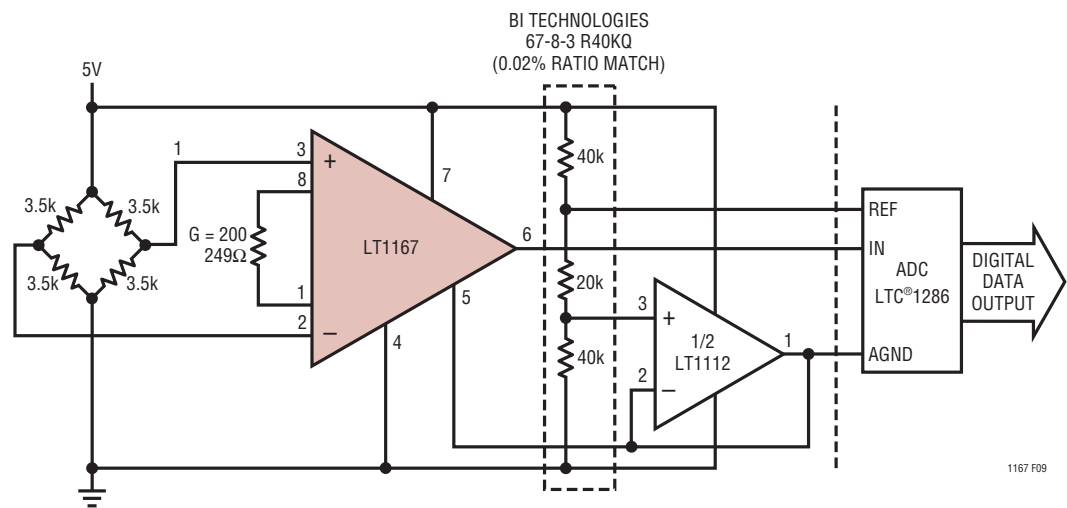
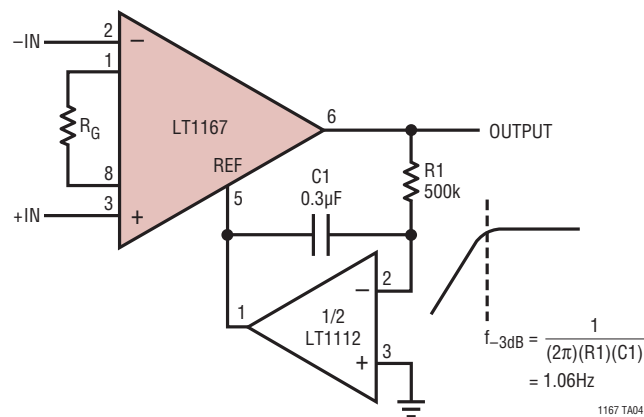


Figure 9. Single Supply Bridge Amplifier

TYPICAL APPLICATION

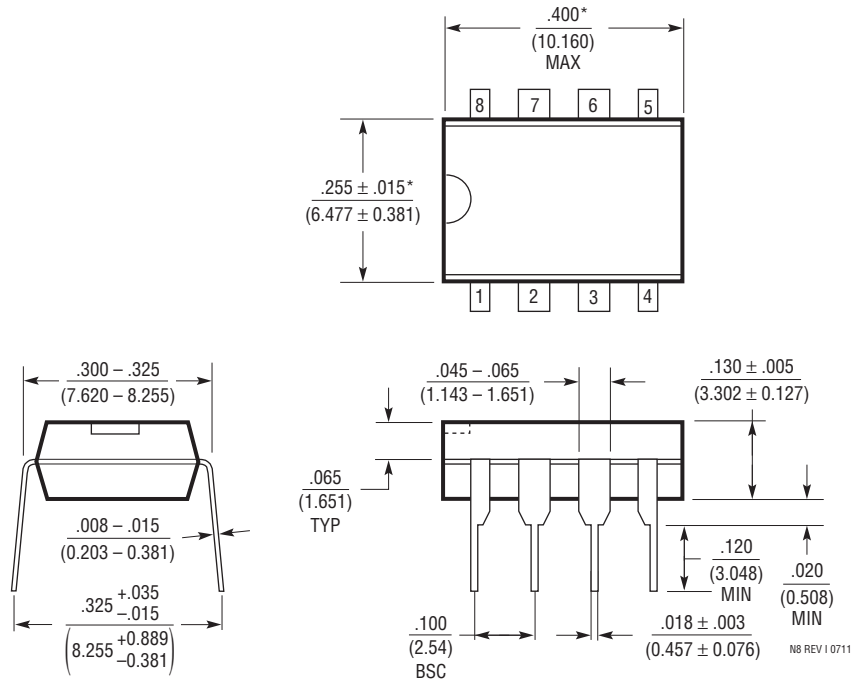
AC Coupled Instrumentation Amplifier



PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

N8 Package 8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510 Rev I)



NOTE:

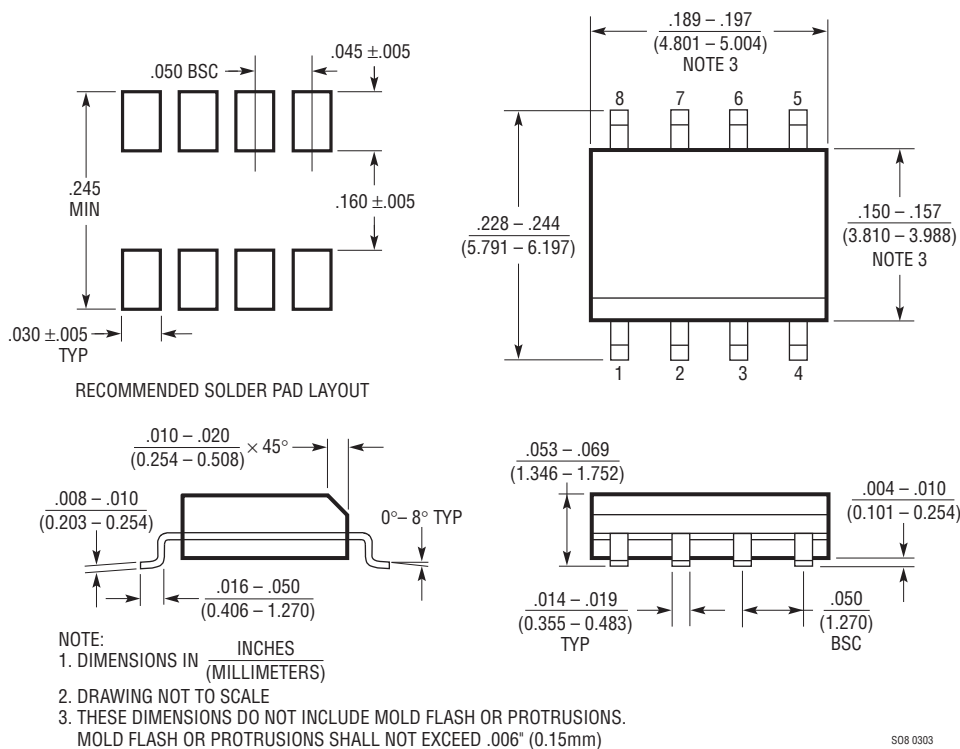
1. DIMENSIONS ARE $\frac{\text{INCHES}}{\text{MILLIMETERS}}$

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)

PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)

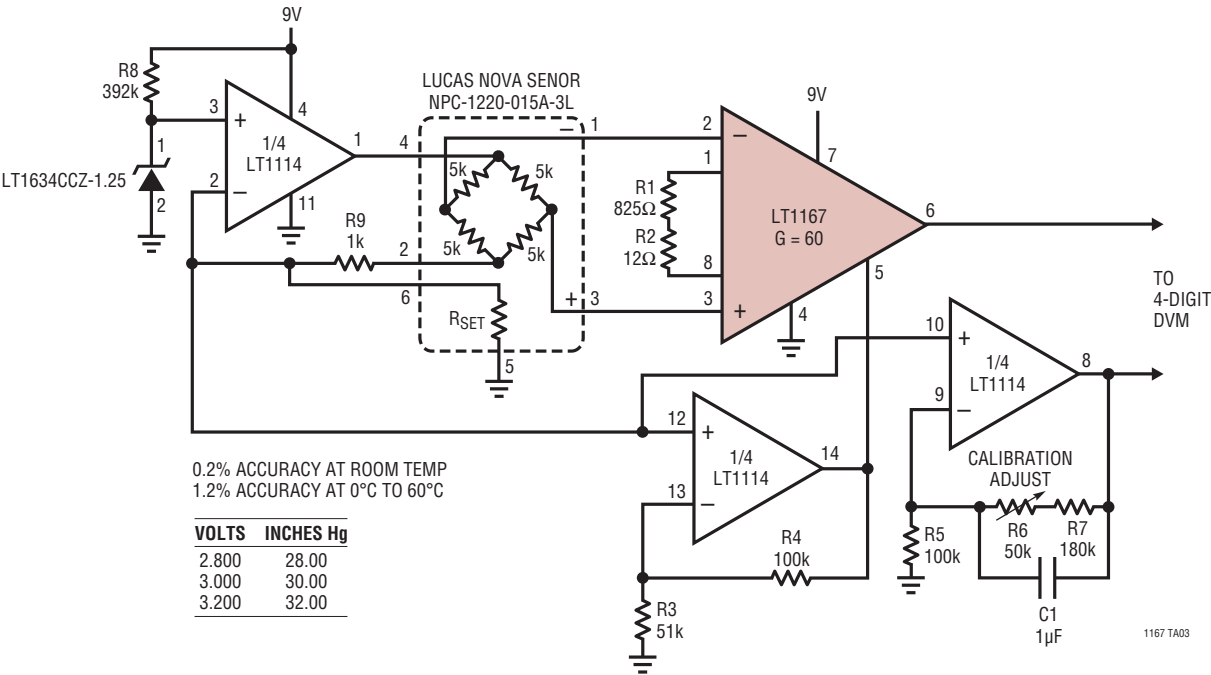


REVISION HISTORY (Revision history begins at Rev B)

REV	DATE	DESCRIPTION	PAGE NUMBER
B	01/11	Added LT1167-1 to Description, Absolute Maximum Ratings, Order Information, Electrical Characteristics and Applications Information Section	1-6, 15
C	08/11	Correction to TYP specification for SR from 12 to 1.2 Columns shifted to left in CMRR specification	4 4, 5

TYPICAL APPLICATION

4-Digit Pressure Sensor



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1100	Precision Chopper-Stabilized Instrumentation Amplifier	Best DC Accuracy
LT1101	Precision, Micropower, Single Supply Instrumentation Amplifier	Fixed Gain of 10 or 100, $I_S < 105\mu A$
LT1102	High Speed, JFET Instrumentation Amplifier	Fixed Gain of 10 or 100, 30V/ μs Slew Rate
LT1168	Low Power, Single Resistor Programmable Instrumentation Amplifier	$I_{SUPPLY} = 530\mu A$ Max
LTC1418	14-Bit, Low Power, 200ksps ADC with Serial and Parallel I/O	Single Supply 5V or $\pm 5V$ Operation, $\pm 1.5LSB$ INL and $\pm 1LSB$ DNL Max
LT1460	Precision Series Reference	Micropower; 2.5V, 5V, 10V Versions; High Precision
LT1468	16-Bit Accurate Op Amp, Low Noise Fast Settling	16-Bit Accuracy at Low and High Frequencies, 90MHz GBW, 22V/ μs , 900ns Settling
LTC1562	Active RC Filter	Lowpass, Bandpass, Highpass Responses; Low Noise, Low Distortion, Four 2nd Order Filter Sections
LTC1605	16-Bit, 100ksps, Sampling ADC	Single 5V Supply, Bipolar Input Range: $\pm 10V$, Power Dissipation: 55mW Typ